

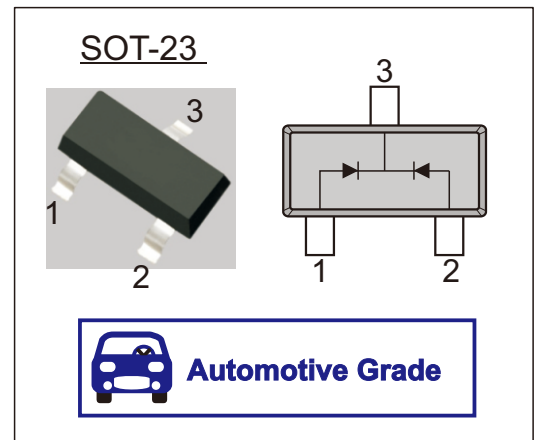
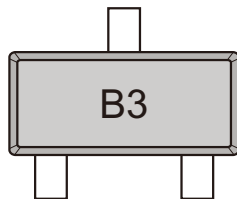


## Switching Diodes

### FEATURES

- Low forward voltage :  $V_F(3) = 0.9 \text{ V(Typ.)}$
- Fast reverse recovery time :  $t_{rr} = 1.6 \text{ ns(Typ.)}$
- Small Total Capacitance :  $C_T = 0.9\text{pF(Typ.)}$
- Meets MSL 1 Requirements
- Qualified to AEC-Q101 Standards for High Reliability

**MARKING:** B3



## MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak Reverse voltage	$V_{RM}$	85	V
DC Blocking Voltage	$V_R$	80	V
Average Rectified Output Current	$I_o$	100	mA
Peak forward surge current	$I_{FM}$	300	mA
Power Dissipation	$P_D$	150	mW
Operating Junction Temperature range	$T_J$	-55 ~ +150	°C
Storage temperature range	$T_{STG}$	-55 ~ +150	°C

## ELECTRICAL CHARACTERISTICS ( TA=25°C unless otherwise noted )

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse breakdown voltage	$V_R$	$I_R=100\mu\text{A}$	80			V
Forward voltage	$V_{F1}$	$I_F=1 \text{ mA}$		0.6		V
	$V_{F2}$	$I_F=10\text{mA}$		0.72		V
	$V_{F3}$	$I_F=100\text{mA}$		0.9	1.2	V
Reverse voltage leakage current	$I_{R1}$	$V_R=30\text{V}$			0.1	$\mu\text{A}$
	$I_{R2}$	$V_R=80\text{V}$			0.5	$\mu\text{A}$
Capacitance between terminals	$C_T$	$V_R=0\text{V}, f=1\text{MHz}$		0.9	3.0	pF
Reverse recovery time	$t_{rr}$	$I_F=10\text{mA}, V_R=6\text{V}, I_{rr}=0.1I_R, R=100$		1.6	4.0	ns



## Typical Performance Characteristics

Fig.1 Power Derating Curve

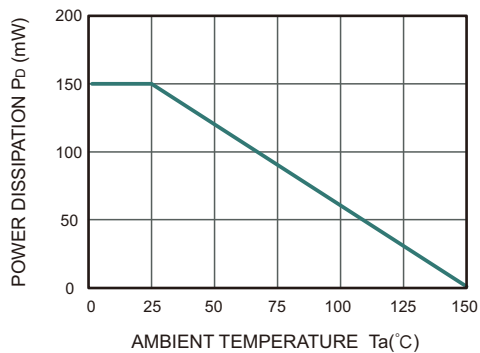


Fig.2 Reverse Characteristics

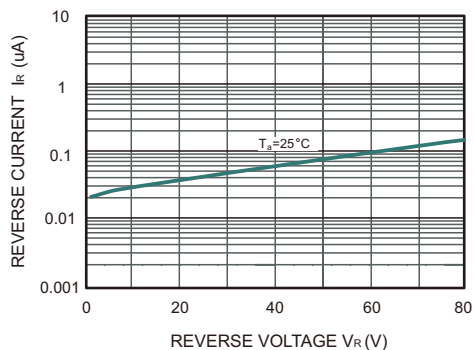


Fig.3 Forward Characteristics

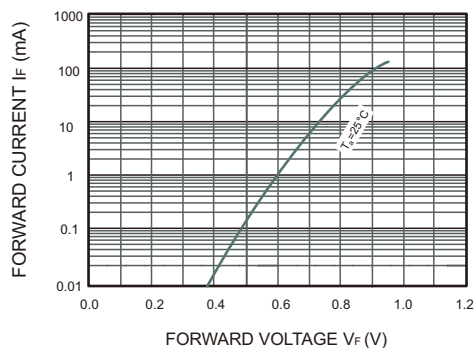
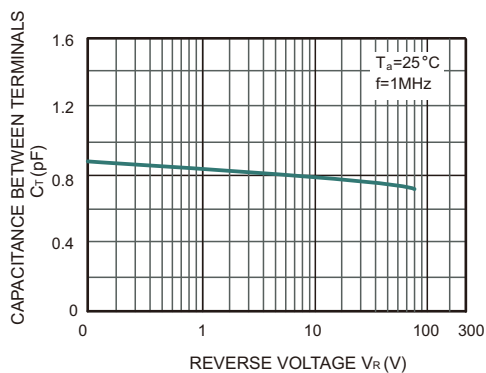
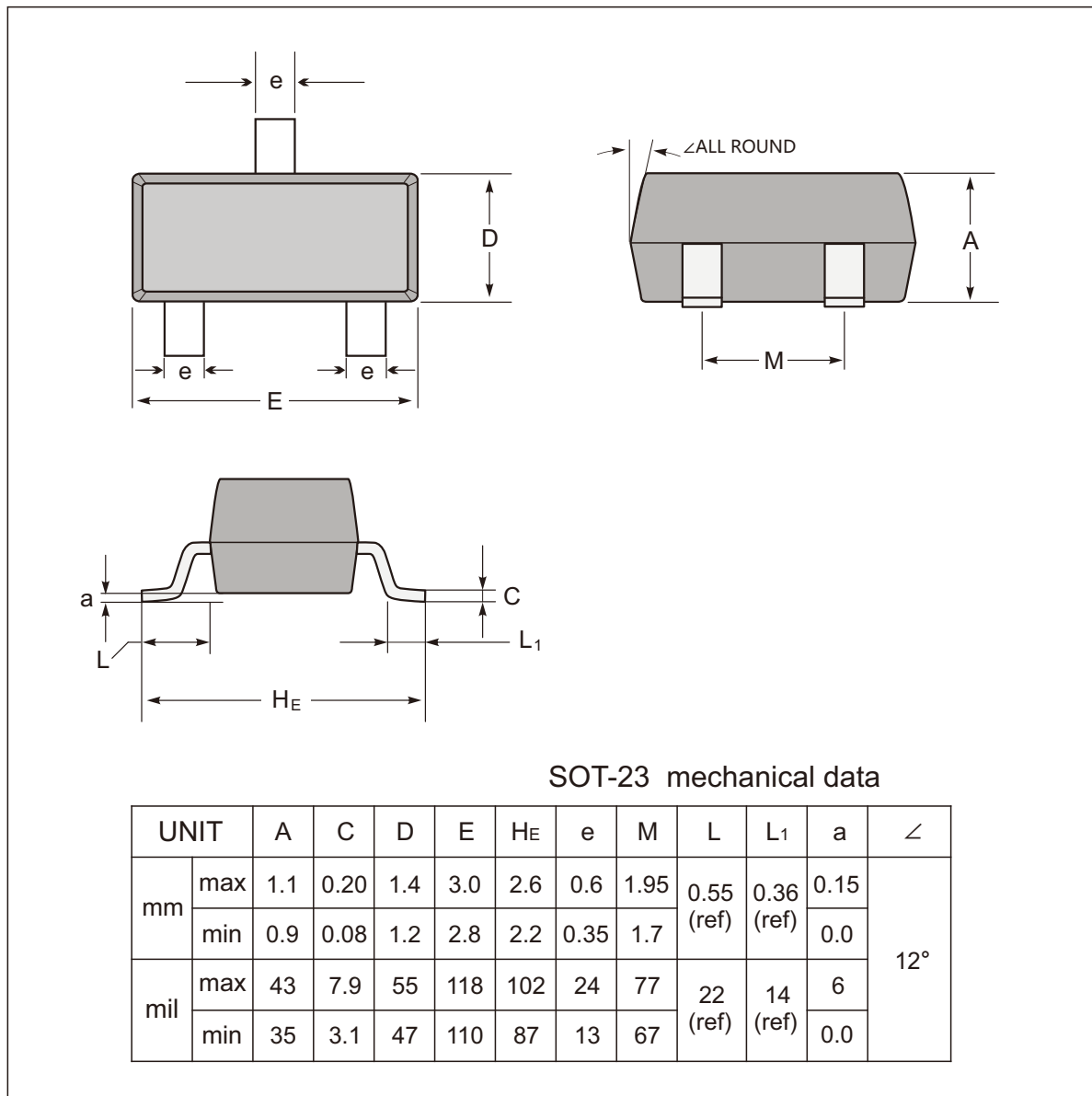


Fig.4 Capacitance Characteristics

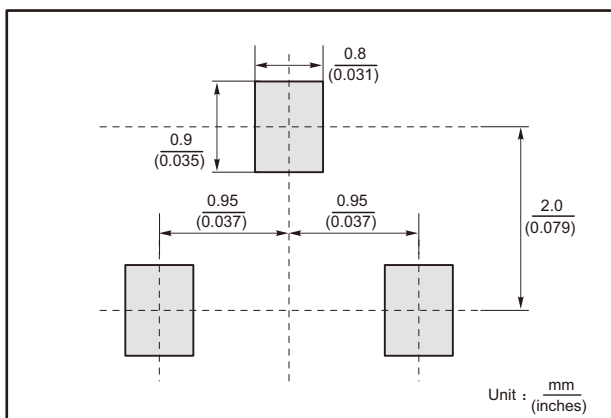




### SOT-23 Package Outline Dimensions



#### The recommended mounting pad size



#### Marking

Type number	Marking code
AT-1SS184WD	B3



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